

## SOT-23 Plastic-Encapsulate Transistors

TRANSISTOR(NPN)

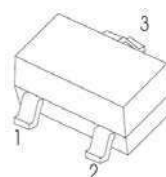
**MMBT6428**

**MMBT6429**

### MAXIMUM RATINGS

Rating	Symbol	Value		Unit
		6428	6429	
Collector–Emitter Voltage	$V_{CEO}$	50	45	Vdc
Collector–Base Voltage	$V_{CBO}$	60	55	Vdc
Emitter–Base Voltage	$V_{EBO}$	6.0		Vdc
Collector Current — Continuous	$I_C$	200		mAdc

SOT-23



1. BASE
2. EMITTER
3. COLLECTOR

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board, (1) $T_A = 25^\circ\text{C}$	$P_D$	225	mW
Derate above $25^\circ\text{C}$		1.8	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate, (2) $T_A = 25^\circ\text{C}$	$P_D$	300	mW
Derate above $25^\circ\text{C}$		2.4	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	$T_J, T_{stg}$	–55 to +150	$^\circ\text{C}$

### DEVICE MARKING

MMBT6428 = 1KM, MMBT6429 = 1L

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Max	Unit
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### OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage(3) ( $I_C = 1.0\text{ mAdc}, I_B = 0$ )	$V_{(BR)CEO}$	50	—	Vdc
( $I_C = 1.0\text{ mAdc}, I_B = 0$ )	MMBT6428	50	—	
( $I_C = 1.0\text{ mAdc}, I_B = 0$ )	MMBT6429	45	—	
Collector–Base Breakdown Voltage ( $I_C = 0.1\text{ mAdc}, I_E = 0$ )	$V_{(BR)CBO}$	60	—	Vdc
( $I_C = 0.1\text{ mAdc}, I_E = 0$ )	MMBT6428	60	—	
( $I_C = 0.1\text{ mAdc}, I_E = 0$ )	MMBT6429	55	—	
Collector Cutoff Current ( $V_{CE} = 30\text{Vdc},$ )	$I_{CBO}$	—	0.1	$\mu\text{Adc}$
Collector Cutoff Current ( $V_{CB} = 30\text{Vdc}, I_E = 0$ )	$I_{CBO}$	—	0.01	$\mu\text{Adc}$
Emitter Cutoff Current ( $V_{EB} = 5.0\text{Vdc}, I_C = 0$ )	$I_{EBO}$	—	0.01	$\mu\text{Adc}$

1. FR–5 = 1.0 x 0.75 x 0.062 in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

**Typical Characteristics**

**MMBT6428 MMBT6429**

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted) (Continued)

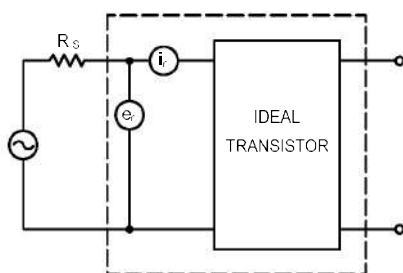
Characteristic	Symbol	Min	Max	Unit
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**ON CHARACTERISTICS**

DC Current Gain ( $I_C = 0.01 \text{ mAdc}$ , $V_{CE} = 5.0 \text{ Vdc}$ )	$h_{FE}$	250	—	—
	MMBT6428	250	—	
	MMBT6429	500	—	
( $I_C = 0.1 \text{ mAdc}$ , $V_{CE} = 5.0 \text{ Vdc}$ )	MMBT6428	250	650	
	MMBT6429	500	1250	
( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 5.0 \text{ Vdc}$ )	MMBT6428	250	—	
	MMBT6429	500	—	
( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 5.0 \text{ Vdc}$ )	MMBT6428	250	—	
	MMBT6429	500	—	
Collector–Emitter Saturation Voltage ( $I_C = 10 \text{ mAdc}$ , $I_B = 0.5 \text{ mAdc}$ )	$V_{CE(sat)}$	—	0.2	Vdc
( $I_C = 100 \text{ mAdc}$ , $I_B = 0.5 \text{ mAdc}$ )		—	0.6	
Base–Emitter On Voltage ( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 5.0 \text{ mAdc}$ )	$V_{BE(on)}$	0.56	0.66	Vdc

**SMALL–SIGNAL CHARACTERISTICS**

Current Gain–Bandwidth Product ( $V_{CE} = 5.0 \text{ Vdc}$ , $I_C = 1.0 \text{ mAdc}$ , $f = 100 \text{ MHz}$ )	$f_T$	100	700	MHz
Output Capacitance ( $V_{CB} = 10 \text{ Vdc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{obo}$	—	3.0	pF
Input Capacitance ( $V_{EB} = 0.5 \text{ Vdc}$ , $I_C = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{ibo}$	—	8.0	pF

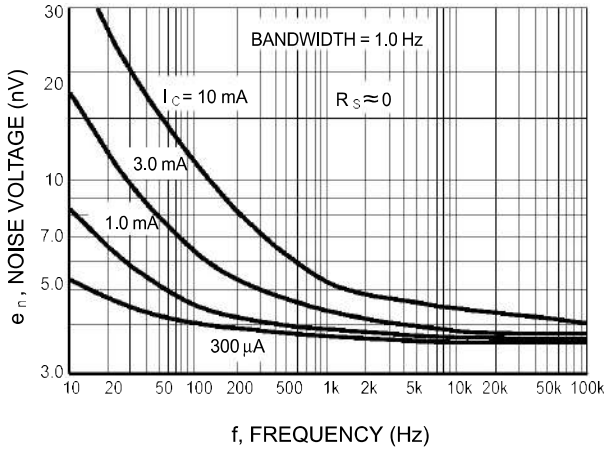


**Figure 1. Transistor Noise Model**

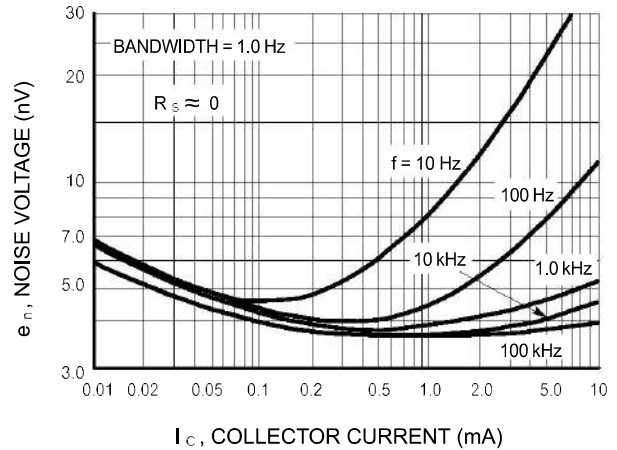
**NOISE CHARACTERISTICS**

( $V_{CE} = 5.0 \text{ Vdc}$ ,  $T_A = 25^\circ\text{C}$ )

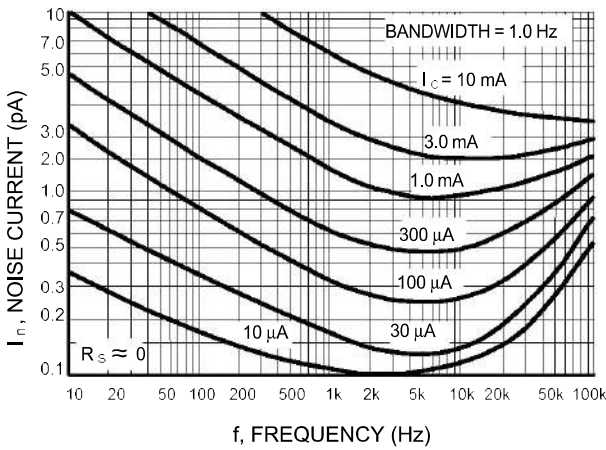
**NOISE VOLTAGE**



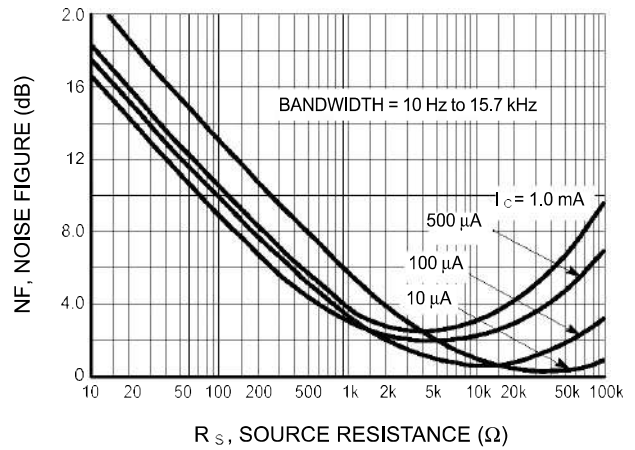
**Figure 2. Effects of Frequency**



**Figure 3. Effects of Collector Current**

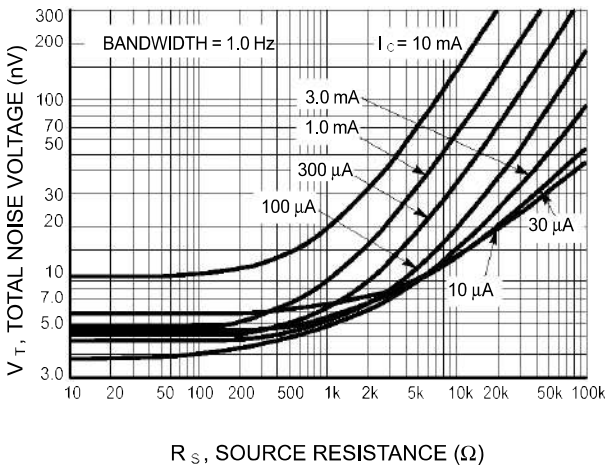


**Figure 4. Noise Current**

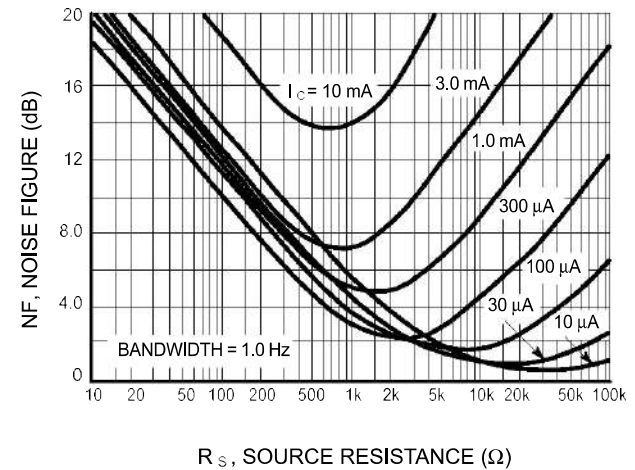


**Figure 5. Wideband Noise Figure**

**100 Hz NOISE DATA**

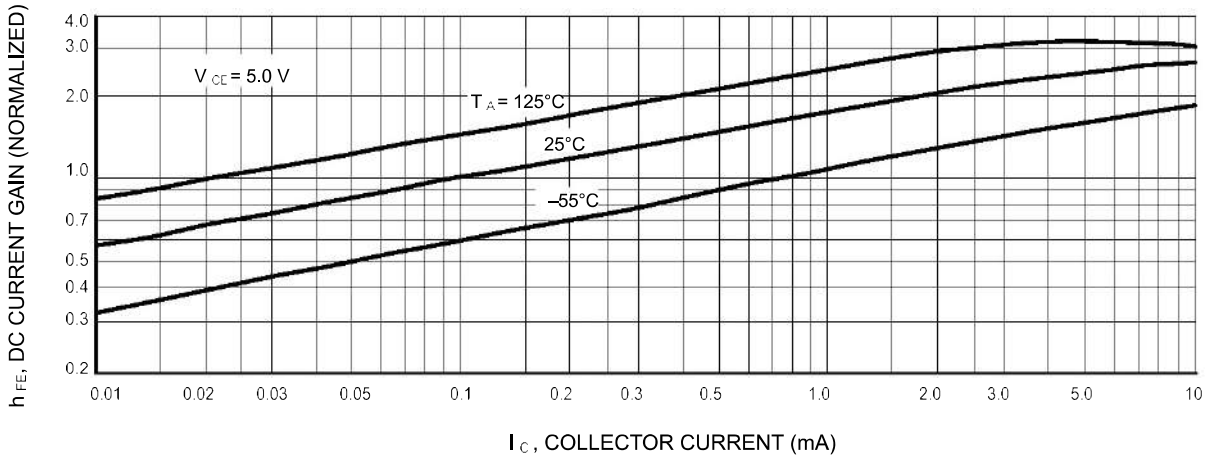


**Figure 6. Total Noise Voltage**

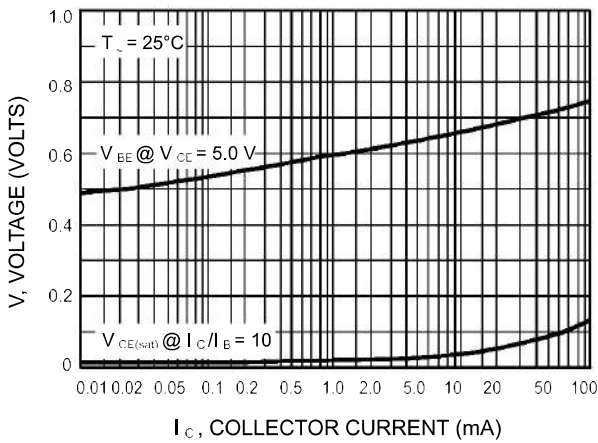


**Figure 7. Noise Figure**

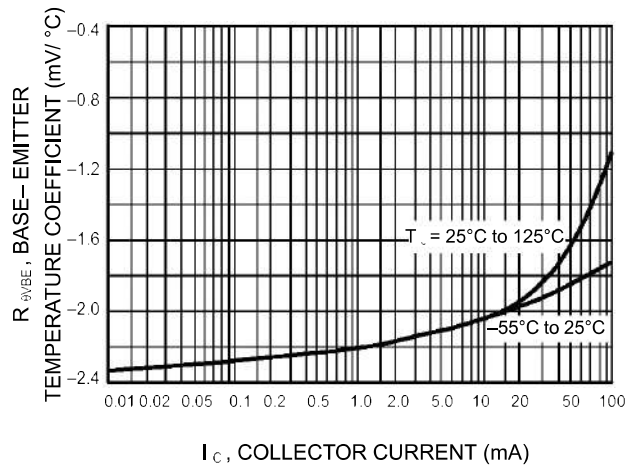
**Typical Characteristics**  
**MMBT6428 MMBT6429**



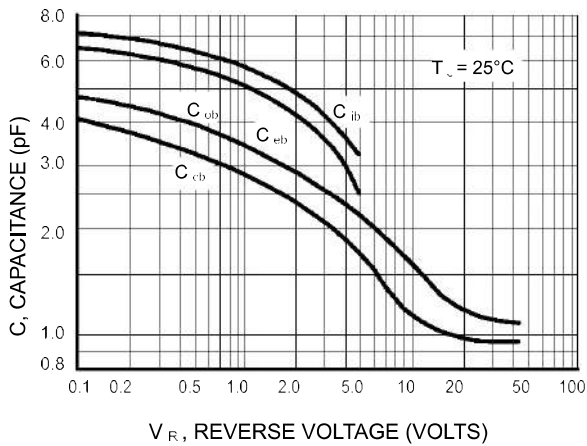
**Figure 8. DC Current Gain**



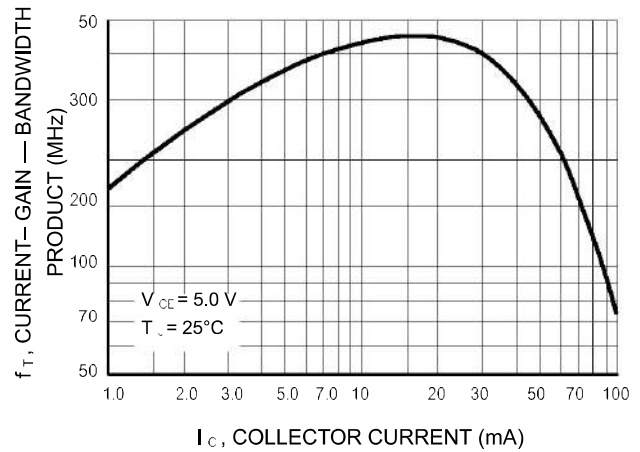
**Figure 9. "On" Voltages**



**Figure 10. Temperature Coefficients**

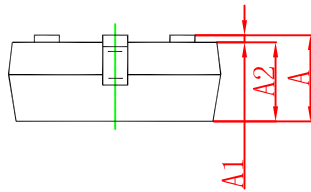
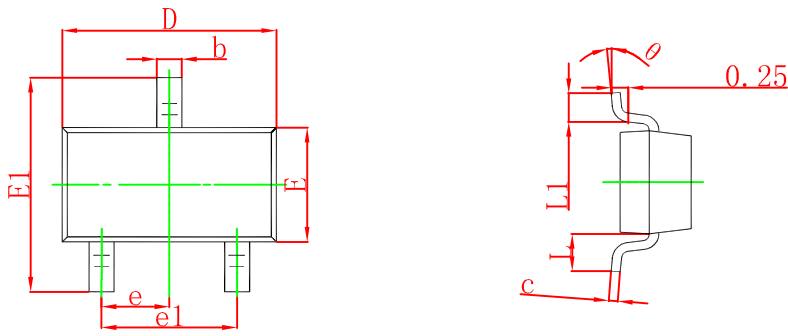


**Figure 11. Capacitance**



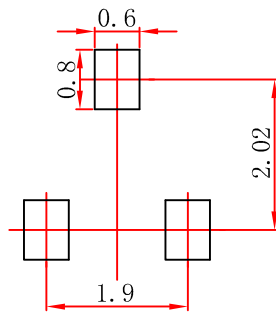
**Figure 12. Current-Gain — Bandwidth Product**

**SOT-23 Package Outline Dimensions**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

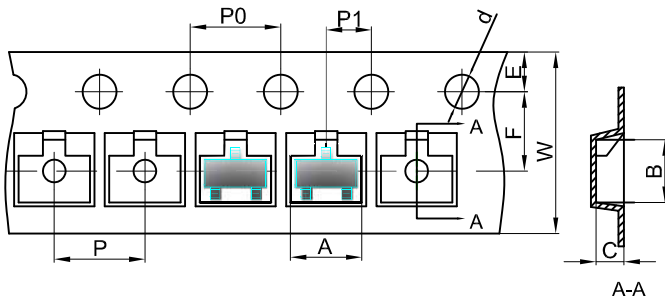
**SOT-23 Suggested Pad Layout**



- Note:
1. Controlling dimension: in millimeters.
  2. General tolerance: ± 0.05mm.
  3. The pad layout is for reference purposes only.

**SOT-23 Tape and Reel**

SOT-23 Embossed Carrier Tape



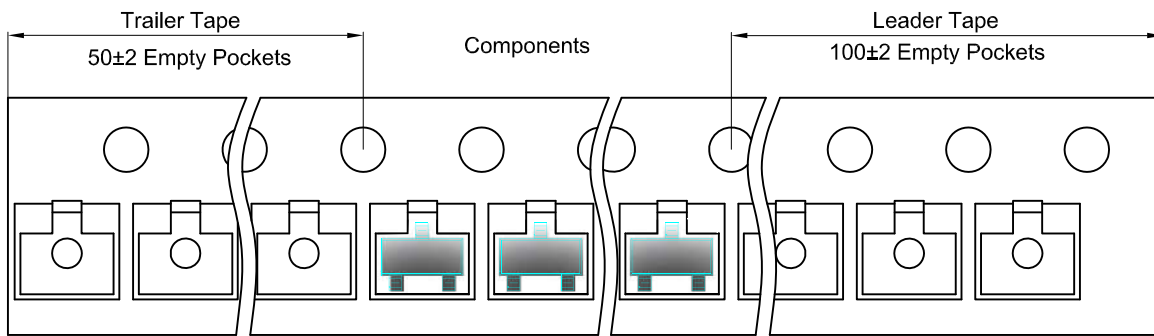
Packaging Description:

SOT-23 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

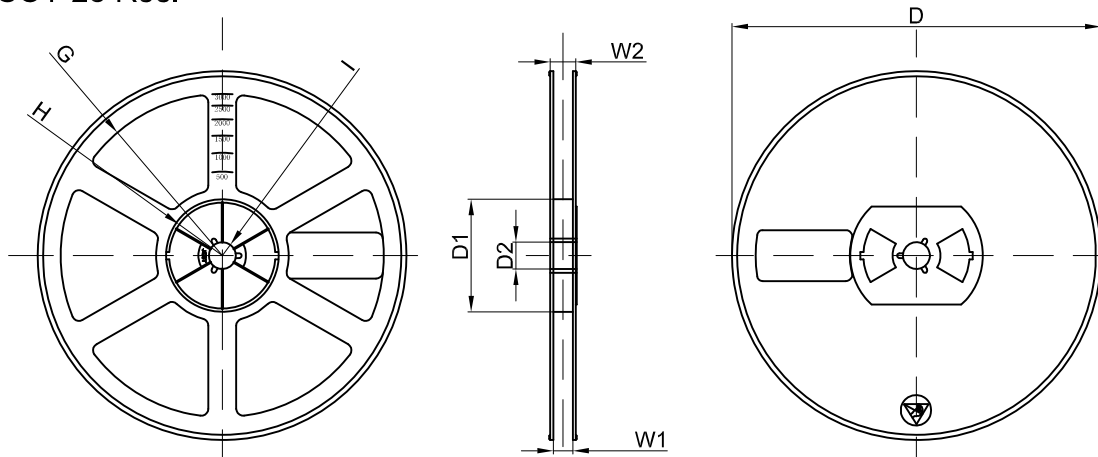
Dimensions are in millimeter

Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

**SOT-23 Tape Leader and Trailer**



**SOT-23 Reel**



Dimensions are in millimeter

Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	45,000 pcs	203×203×195	180,000 pcs	438×438×220	